3300 W 54 V bi-directional phase-shift full-bridge with 600 V CoolMOS™ CFD7 and XMC™

EVAL_3K3W_BIDI_PSFB





General description

Introduction

This Infineon evaluation board (EVAL_3K3W_BIDI_PSFB) represents a complete system solution for a 3300 W telecom or battery charging DC-DC converter, which achieves 98 percent efficiency peak. The DC-DC converter comprises a ZVS PSFB with bi-directional capability (patent pending).

To achieve the high efficiency results the evaluation board features several Infineon components:

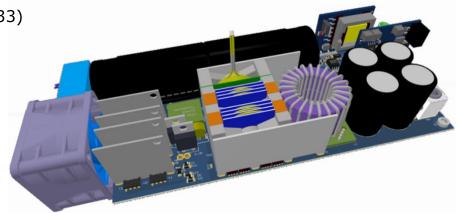
- > 75 mΩ 600 V CoolMOS™ CFD7 (IPL60R075CFD7) in the high voltage (HV) bridge
- 9.3 mΩ OptiMOS™ 5 150 V in Super SO-8 package (BSC093N15NS5) in the low voltage (LV) bridge
- → EiceDRIVER™ gate driver IC (2EDS8265H safety isolated and 2EDF7275F functional isolated)
- XMC[™] microcontroller for control implementation (XMC4200-F64k256 BA)
- Quasi-resonant flyback controller (ICE5QSAG) with external 800 V CoolMOS™ P7 4.5 Ω (IPU80R4K5P7)
- CoolSiC[™] Schottky diode 650V G6 (IDH08G65C6)
- Medium power Schottky diode (BAT165)
- DC-DC step-down voltage regulator (IFX91041EJV33)

Board parametrics:

Input voltage: $350 V_{DC} - 415 V_{DC}$ Output voltage: $60 V_{DC} - 40 V_{DC}$

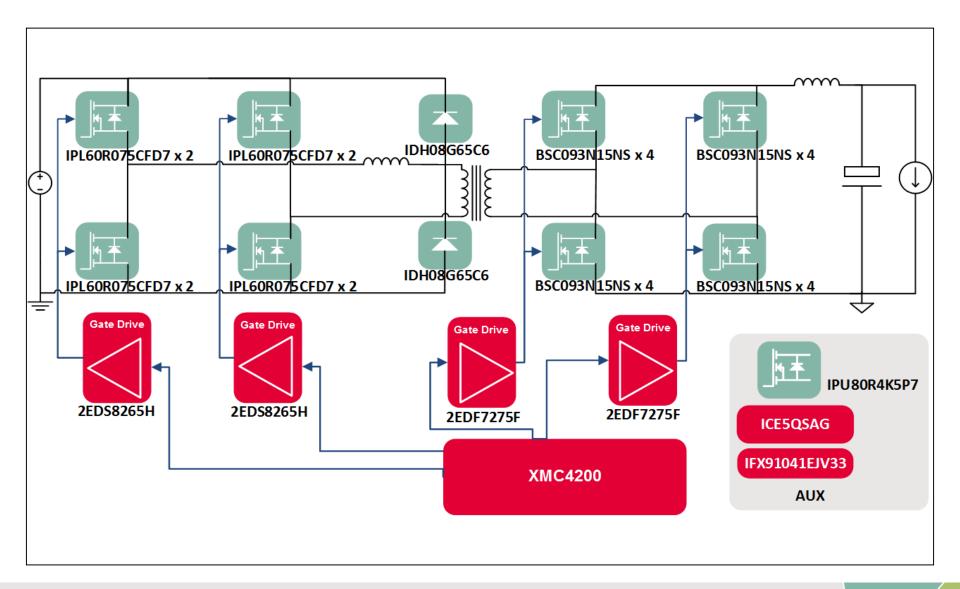
Output power: 3300 W Switching frequency: 100 kHz

Peak efficiency: 98%



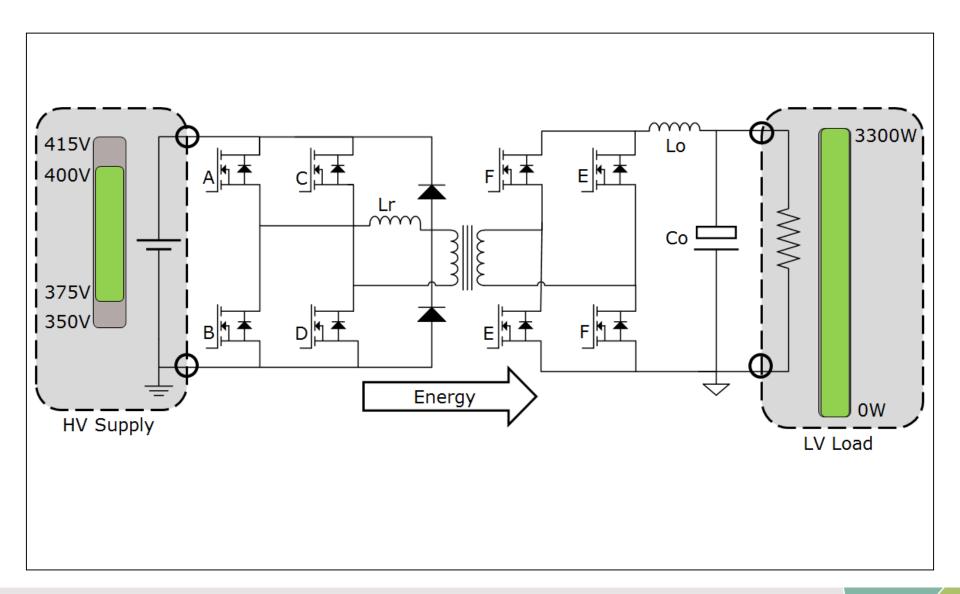


Simplified diagram



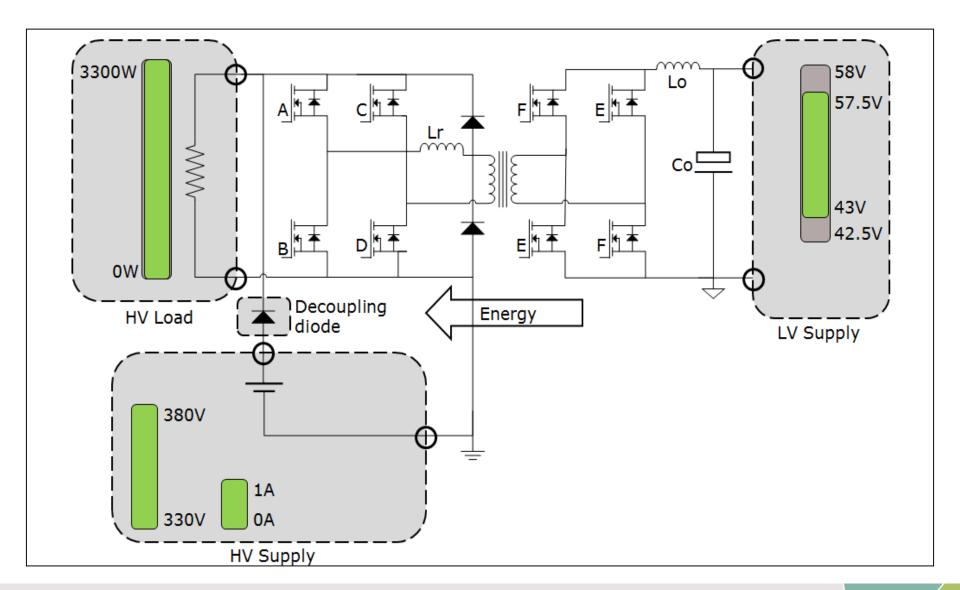


Buck operation



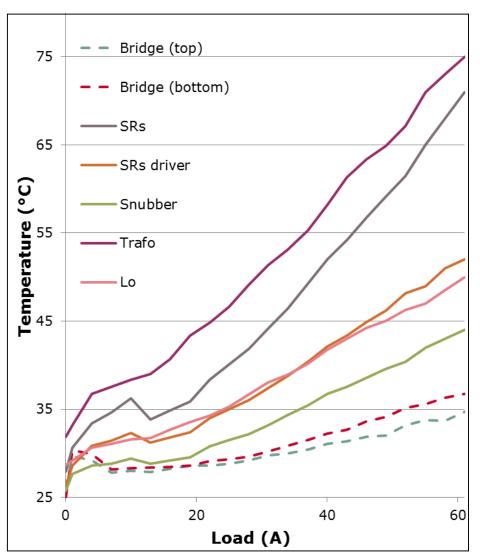


Boost operation

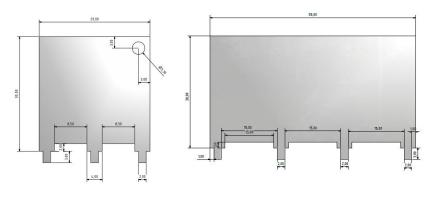




Innovative cooling for SMD devices



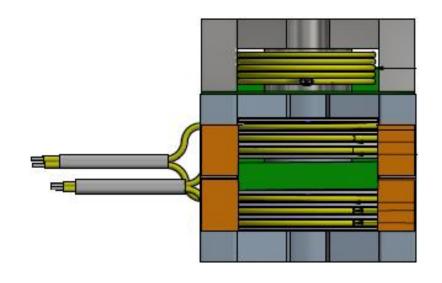


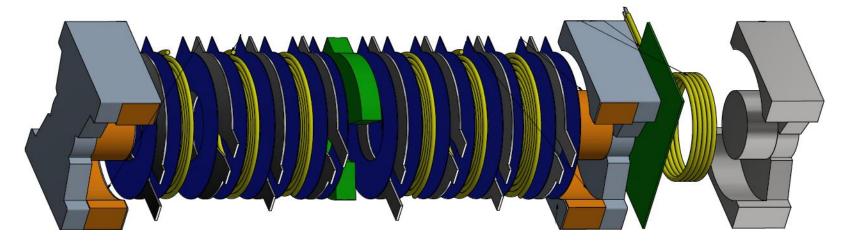




Stacked magnetic structure

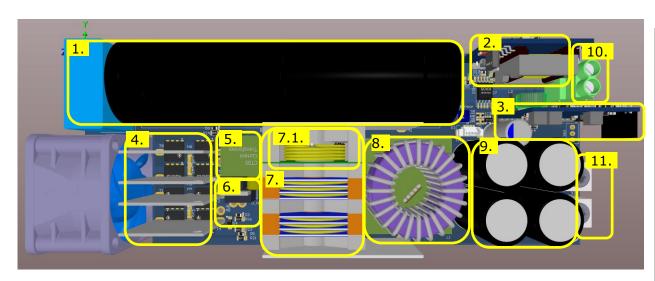
Item	Value	Manufacturer
Lm	650 µH	ICE
Lr	11 μΗ	ICE
Transformer core	PQ35 / 28	DMR95 DMGC
Lr core	PQI35 / 23	DMR95 DMGC
Primary wire	7 x 0.3 mm Litz	Furukawa
Lr wire	120 x 0.1 mm Litz	
Secondary wire	0.5 mm copper plate	

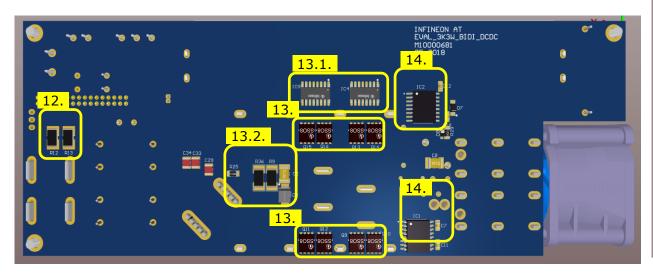






Board distribution





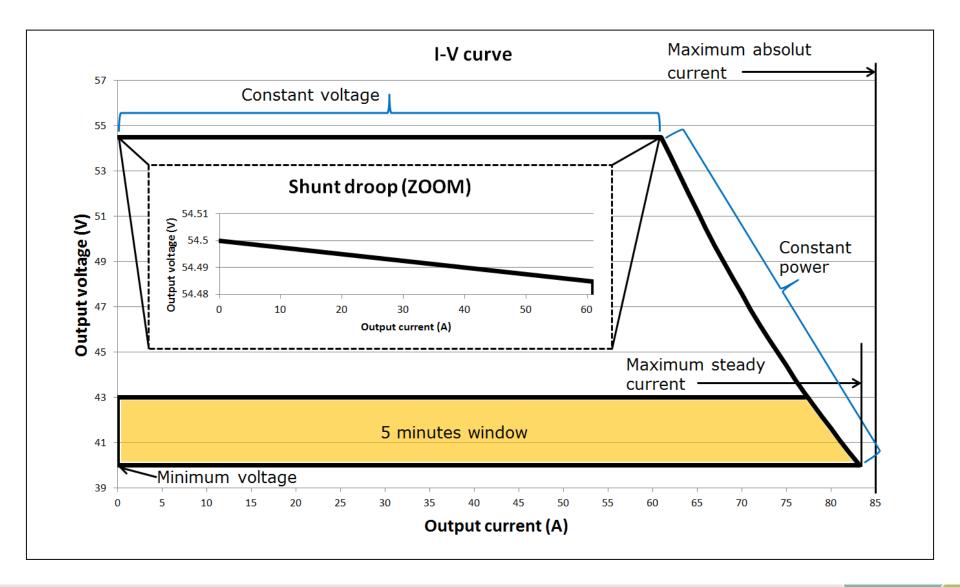
Functional blocks

- 1. HV Bulk
- Bias supply
- 3. Control card
- 4. HV bridge
- 5. C. Sence
- 6. C. Diodes
- 7. Maintransformer
 - 7.1. LR
- 8. Output choke
- 9. Output capasitor
- 10. Input connector
- 11. Output connector
- 12. Output shunt
- 13. Synchronous Rectification
 - 13.1. Functional isolated Driver (SR)
 - 13.2. Snubber (SR)
- 14. Reinforced isolated Drivers (Bridge)

*SR - Synchronous Rectification

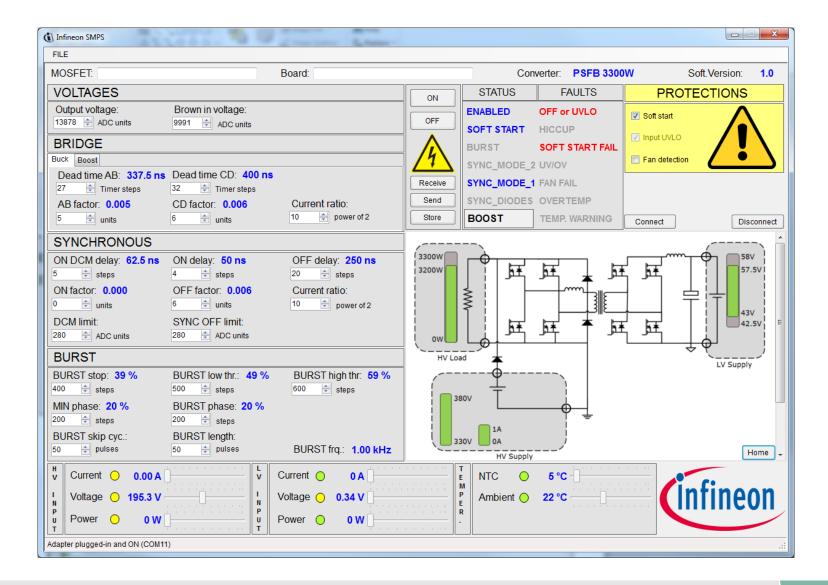


Buck operation current-voltage curve





User interface



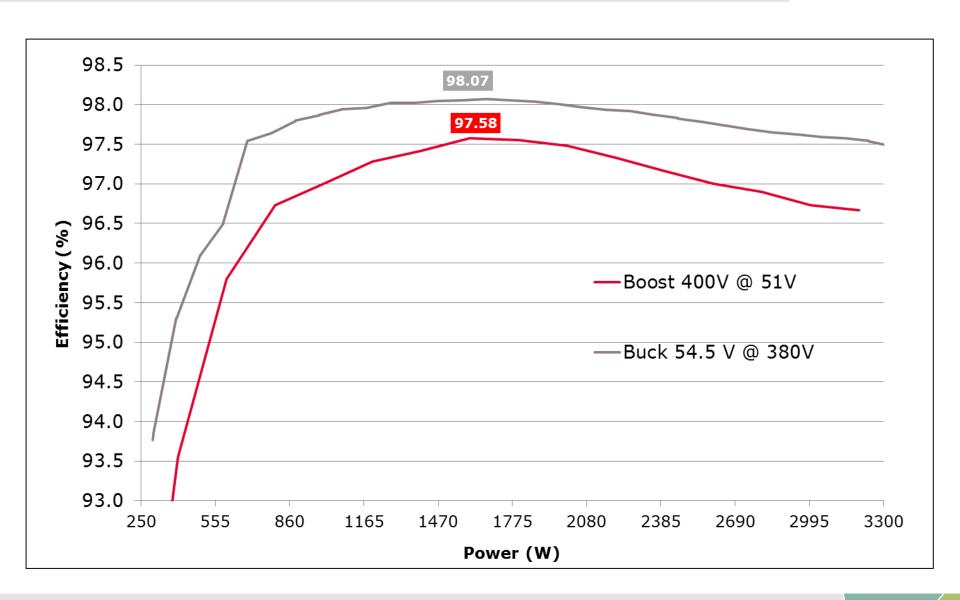


Summary of specifications

Test	Conditions	Specification
Efficiency test	380 V input, 54.5 V output	$\eta_{pk} = 98\%$ at 1500 W (50% load)
Output voltage		60 V - 40 V
Steady-state V _{out} ripple	380 V input, 54.5 V output	$ \Delta V_{out} $ less than 200 m V_{pk-pk}
Brown-out		370 V on – 350 V off 415 V off – 390 V on
Load transient	$5 A \leftrightarrow 31 A$, $0.5 A/\mu s$ $31 A \leftrightarrow 61 A$, $0.5 A/\mu s$	$ \Delta V_{out} $ less than 450 m V_{pk}
	5 min. at 77 A - 83 A 1 ms at 83 -85 A	Shut down and resume after 5 min.
ОСР	20 μs at 85 A	Shut down and latch
	Output terminals in short-circuit	Detection within switching cycle Shut down and latch

Efficiency Bias and fan included

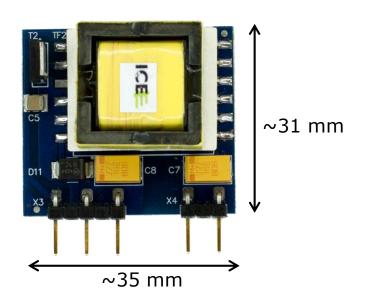




Bias board KIT_6W_12V_P7_950V







Ordering code: KIT_6W_12V_P7_950V

Board components

- CoolSET™ standalone controller (ICE5QSAG)
- 950 V CoolMOS™ P7 SJ MOSFET (IPU95R3K7P7)

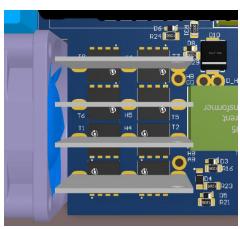
Board specifications

- Input voltage: 90 V_{DC} 400 V_{DC}
- Output voltage: 12 V_{DC} (prim. and sec. side)
- Output power max.: 6 W (prim. + sec. side)

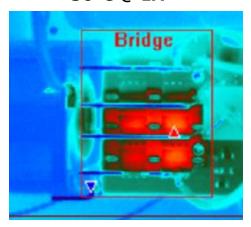
Auxiliary supply solution featuring off-line SMPS current mode controller IC with an 950 V CoolMOS™ SJ MOSFET

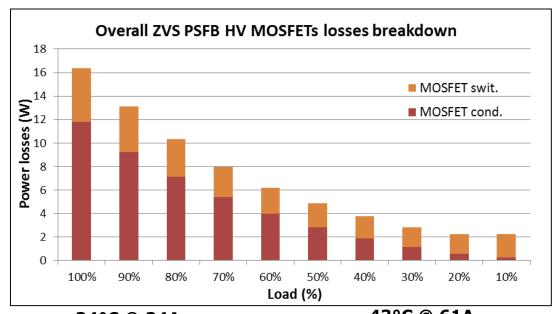
600 V CoolMOS™ CFD7 (IPL60R075CFD7) **HV** bridge MOSFETs





36°C @ 1A

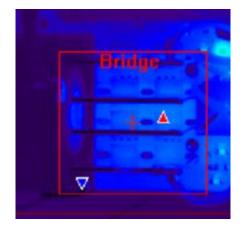




34°C @ 34A

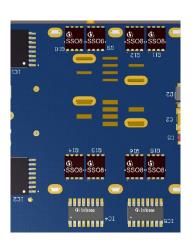


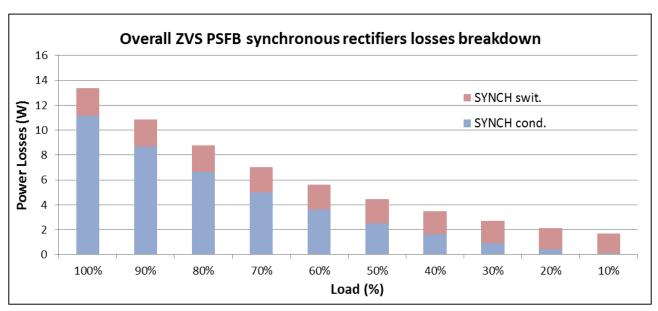
43°C @ 61A



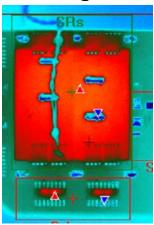
OptiMOS™ 5 150 V (BSC093N15NS) SR bridge MOSFETs



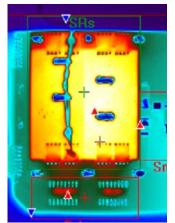




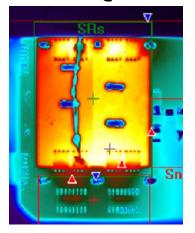
33°C @ 1A



53°C @ 34A

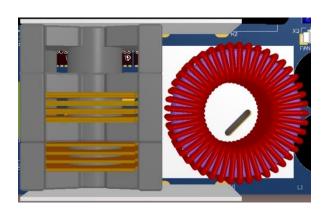


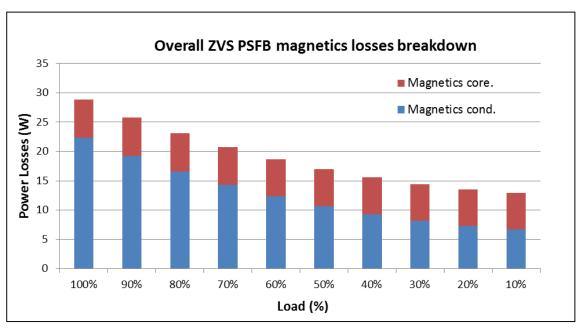
76°C @ 61A



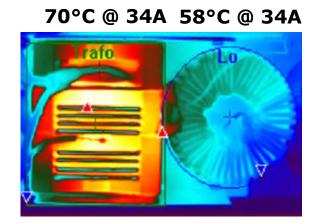
Magnetics: Transformer, resonant inductance and output choke

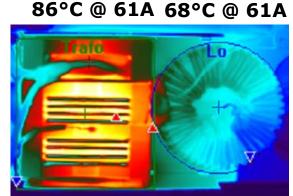






39°C @ 1A 36°C @ 1A







Summary

- The trend in the field of switched mode power supplies (SMPS) in the last years moves towards the increase of power density with an optimized cost. In order to achieve this higher power density, high efficiency is a key parameter since heat dissipation must be minimized
- The 3300 W DC-DC converter evaluation board developed with Infineon semiconductors, is a good example of how to achieve high efficiency level and high power density in telecom and battery charging applications
- Fully resonant topologies, like LLC, are traditionally considered best possible solution for high power, high voltage DC-DC converters. The EVAL_3K3W_BIDI_PSFB demonstrates PSFB topology can achieve similar or equal levels of performance
- Unlike the bi-directional operation in other resonant topologies, the proposed bi-directional operation of PSFB in EVAL_3K3W_BIDI_PSFB does not constrain the design, does not have any impact on efficiency nor requires any additional components
- This telecom or battery charging DC-DC converter allows as well the implementation and test of future Infineon devices and technologies





Support

Technical Material

- > Application Notes
- > Simulation Models
- > Datasheets

> EVAL 3K3W BIDI PSFB

Evaluation Boards

- > Evaluation Boards
- > Demoboards
- > Reference Designs

> www.infineon.com/evaluationboards

Videos

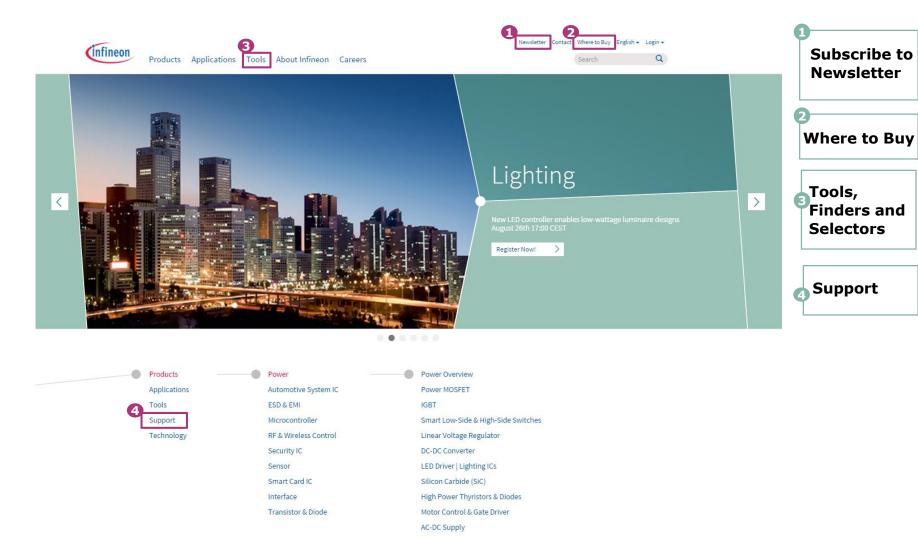
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